TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC4093BP,TC4093BF,TC4093BFN

#### TC4093B Quad 2-Input NAND Schmitt Triggers

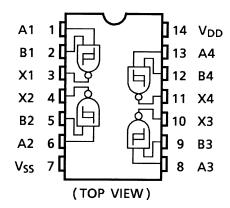
The TC4093B is a quad 2-input NAND gate having Schmitt trigger function for all the input terminals.

Since the circuit threshold voltage varies with rising time and falling time of the input waveform (VP and VN), this gate can be used for a wide variety of applications to line receivers, waveform shaping, astable multivibrators, monosatable multivibrators, etc.

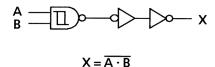
In addtion to regular NAND gates.

As the TC4093B and the TC4011B are identical in pin assignment, they are compatible each other.

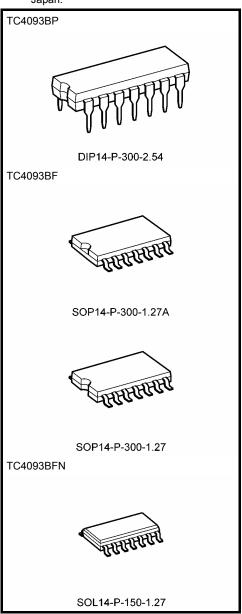
#### **Pin Assignment**



#### **Logic Diagram**



Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

 DIP14-P-300-2.54
 : 0.96 g (typ.)

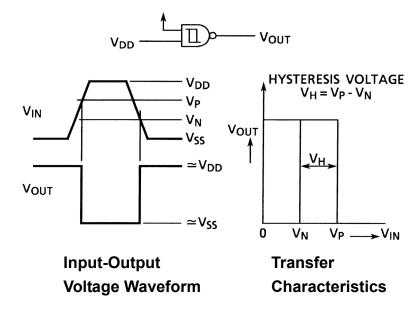
 SOP14-P-300-1.27A
 : 0.18 g (typ.)

 SOP14-P-300-1.27
 : 0.18 g (typ.)

 SOL14-P-150-1.27
 : 0.12 g (typ.)



#### **Input-Output Characteristic**



#### **Absolute Maximum Ratings (Note)**

Characteristics	Symbol	Rating	Unit
DC supply voltage	$V_{DD}$	V <sub>SS</sub> - 0.5~V <sub>SS</sub> + 20	V
Input voltage	V <sub>IN</sub>	V <sub>SS</sub> – 0.5~V <sub>DD</sub> + 0.5	٧
Output voltage	V <sub>OUT</sub>	V <sub>SS</sub> – 0.5~V <sub>DD</sub> + 0.5	<b>V</b>
DC input current	I <sub>IN</sub>	±10	mA
Power dissipation	P <sub>D</sub>	300 (DIP)/180 (SOIC)	mW
Operating temperature range	T <sub>opr</sub>	<b>−40~85</b>	°C
Storage temperature range	T <sub>stg</sub>	−65 <b>~</b> 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

## **Recommended Operating Conditions (VSS = 0 V) (Note)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
DC supply voltage	$V_{DD}$	_	3	_	18	V
Input voltage	V <sub>IN</sub>	_	0	_	$V_{DD}$	V

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Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



# Static Electrical Characteristics ( $V_{SS} = 0 V$ )

01		Sym-	Test Condition		-40°C			25°C		85°C		
Charac	cteristics	bol		V <sub>DD</sub> (V)	Min	Max	Min	Тур.	Max	Min	Max	Unit
High-level voltage	l output	V <sub>OH</sub>	$ I_{OUT}  < 1 \mu A$ $V_{IN} = V_{SS}, V_{DD}$	5 10 15	4.95 9.95 14.95		4.95 9.95 14.95	5.00 10.00 15.00	_ _ _	4.95 9.95 14.95	— — —	V
Low-level voltage	output	V <sub>OL</sub>	$ I_{OUT}  < 1 \mu A$ $V_{IN} = V_{DD}$	5 10 15	_ _ _	0.05 0.05 0.05	_ _ _	0.00 0.00 0.00	0.05 0.05 0.05	_ _ _	0.05 0.05 0.05	V
Output hig	gh current	ІОН	$V_{OH} = 4.6 \text{ V}$ $V_{OH} = 2.5 \text{ V}$ $V_{OH} = 9.5 \text{ V}$ $V_{OH} = 13.5 \text{ V}$ $V_{IN} = V_{SS}, V_{DD}$	5 5 10 15	-0.61 -2.50 -1.50 -4.00	1 1 1 1	-0.51 -2.10 -1.30 -3.40	-1.0 -4.0 -2.2 -9.0		-0.42 -1.70 -1.10 -2.80		mA
Output lov	w current	I <sub>OL</sub>	$V_{OL} = 0.4 \text{ V}$ $V_{OL} = 0.5 \text{ V}$ $V_{OL} = 1.5 \text{ V}$ $V_{IN} = V_{DD}$	5 10 15	0.61 1.5 4.0	— — —	0.51 1.30 3.40	1.5 3.8 15.0	_ _ _	0.42 1.10 2.80	_ _ _	mA
High thres	shold	V <sub>P</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V V <sub>OUT</sub> = 1.0 V, 9.0 V V <sub>OUT</sub> = 1.5 V, 13.5 V	5 10 15	_ _ _	_ _ _	2.05 4.10 6.20	2.8 5.3 7.8	3.55 7.00 10.40	_ _ _	_ _ _	V
Low thres voltage	hold	V <sub>N</sub>	V <sub>OUT</sub> = 0.5 V, 4.5 V V <sub>OUT</sub> = 1.0 V, 9.0 V V <sub>OUT</sub> = 1.5 V, 13.5 V	5 10 15	_ _ _		1.5 3.2 4.8	2.3 4.5 6.6	3.15 6.30 9.30	_ _ _	_ _ _	V
Hysteresis	s voltage	V <sub>H</sub>	_	5 10 15	— — —		0.20 0.30 0.45	0.5 0.8 1.2	0.85 1.40 1.90	_ _ _	— — —	V
Input current	"H" level	l <sub>IH</sub>	V <sub>IH</sub> = 18 V V <sub>IL</sub> = 0 V	18 18	_	0.1 -0.1	_	10 <sup>-5</sup> -10 <sup>-5</sup>	0.1 -0.1	_ _	1.0 -1.0	μА
Quiescent current	t supply	I <sub>DD</sub>	V <sub>IN</sub> = V <sub>SS</sub> , V <sub>DD</sub> (Note)	5 10 15	_ _ _	1 2 4	— — —	0.001 0.002 0.004	1 2 4	_ _ _	7.5 15.0 30.0	μА

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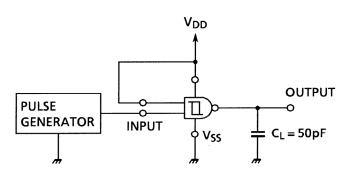
Note: All valid input combinations.

## Dynamic Electrical Characteristics (Ta = 25°C, $V_{SS}$ = 0 V, $C_L$ = 50 pF)

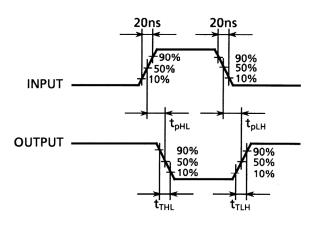
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Output transition time			V <sub>DD</sub> (V)	_	80	200	
(low to high)	tтLH	_	10 15	_	50 40	100 80	ns
Output transition time (high to low)	t <sub>THL</sub>	_	5 10 15	_ _ _	80 50 40	200 100 80	ns
Propagation delay time	t <sub>pLH</sub>	_	5 10 15	_ _ _	130 60 40	260 120 80	ns
Input capacitance	C <sub>IN</sub>	_	•	_	5	7.5	pF

## **Circuit and Waveform for Measurement of Dynamic Characteristics**

#### Circuit Waveform

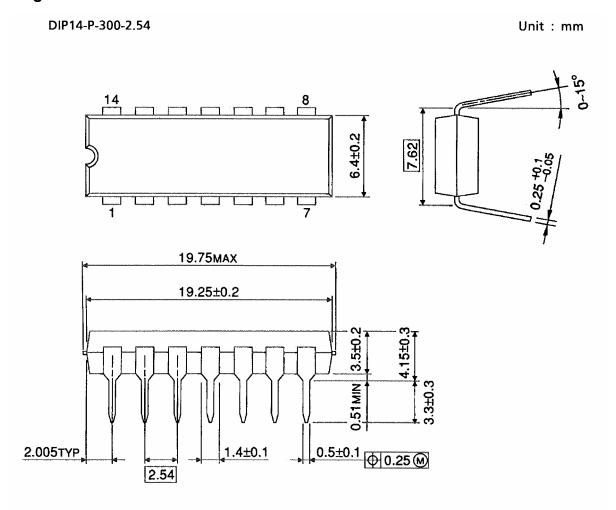


DUTY RATIO = 50%, f = 500kHz





## **Package Dimensions**

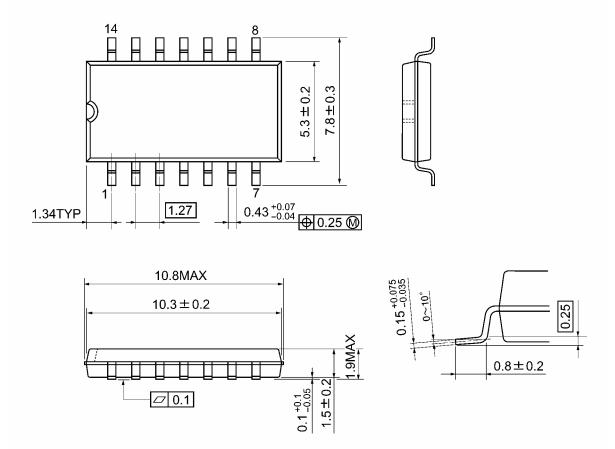


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Weight: 0.96 g (typ.)

## **Package Dimensions**

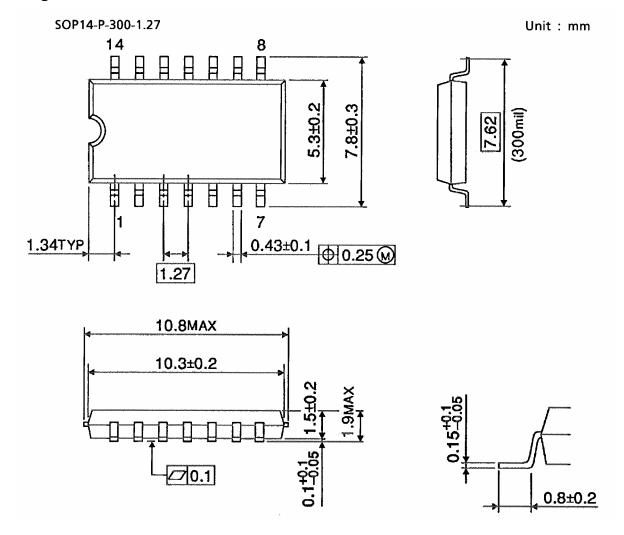
SOP14-P-300-1.27A Unit: mm



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Weight: 0.18 g (typ.)

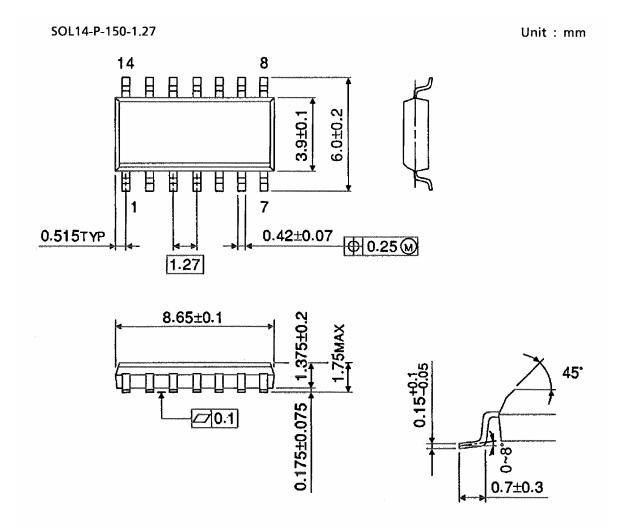
### **Package Dimensions**



Weight: 0.18 g (typ.)

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## **Package Dimensions (Note)**



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Note: This package is not available in Japan.

Weight: 0.12 g (typ.)

Note: Lead (Pb)-Free Packages

DIP14-P-300-2.54 SOP14-P-300-1.27A SOL14-P-150-1.27

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